

74F37 Quad Two-Input NAND Buffer

General Description

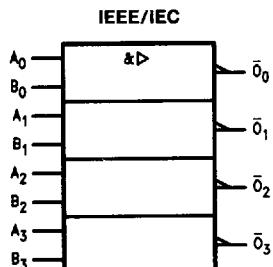
This device contains four independent gates, each of which performs the logic NAND function.

Ordering Code: See Section 11

Commercial	Package Number	Package Description
74F37PC	N14A	14-Lead (0.300" Wide) Molded Dual-In-Line
74F37SC (Note 1)	M14A	14-Lead (0.150" Wide) Molded Small Outline, JEDEC

Note 1: Devices also available in 13" reel. Use suffix = SCX and SJX.

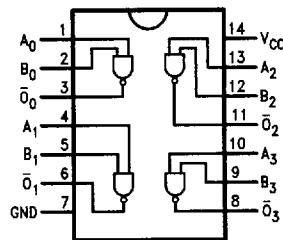
Logic Symbol



TL/F/9464-3

Connection Diagram

Pin Assignment
for SOIC and DIP



TL/F/9464-1

Unit Loading/Fan Out: See Section 2 for U.L. definitions

Pin Names	Description	74F	
		U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_n, B_n \bar{O}_n	Inputs Outputs	1.0/2.0 600/106.6 (80)	20 μ A/-1.2 mA -12 mA/64 mA (48 mA)

Function Table

Inputs		Output
A	B	\bar{O}
L	L	H
L	H	H
H	L	H
H	H	L

H = HIGH Voltage Level
L = LOW Voltage Level

Absolute Maximum Ratings (Note 1)

Storage Temperature	−65°C to +150°C		
Ambient Temperature under Bias	−55°C to +125°C		
Junction Temperature under Bias Plastic	−55°C to +175°C −55°C to +150°C		
V _{CC} Pin Potential to Ground Pin	−0.5V to +7.0V		
Input Voltage (Note 2)	−0.5V to +7.0V		
Input Current (Note 2)	−30 mA to +5.0 mA		
Voltage Applied to Output in HIGH State (with V _{CC} = 0V)	−0.5V to V _{CC}		
Standard Output	−0.5V to +5.5V		
TRI-STATE® Output	−0.5V to +5.5V		

Current Applied to Output
in LOW State (Max) twice the rated I_{OL} (mA)

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature Commercial	0°C to +70°C
Supply Voltage Commercial	+4.5V to +5.5V

DC Electrical Characteristics

Symbol	Parameter	74F			Units	V _{cc}	Conditions
		Min	Typ	Max			
V _{IH}	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V _{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V _{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I _{IN} = −18 mA
V _{OH}	Output HIGH Voltage	74F 10% V _{CC} 74F 10% V _{CC} 74F 5% V _{CC}	2.4 2.0 2.7		V	Min	I _{OH} = −3 mA I _{OH} = −15 mA I _{OH} = −3 mA
V _{OL}	Output LOW Voltage	74F 10% V _{CC}		0.55	V	Min	I _{OL} = 64 mA
I _{IH}	Input HIGH Current	74F		5.0	μA	Max	V _{IN} = 2.7V
I _{BVI}	Input HIGH Current Breakdown Test	74F		7.0	μA	Max	V _{IN} = 7.0V
I _{CEx}	Output HIGH Leakage Current	74F		50	μA	Max	V _{OUT} = V _{CC}
V _{ID}	Input Leakage Test	74F	4.75		V	0.0	I _{ID} = 1.9 μA All Other Pins Grounded
I _{OD}	Output Leakage Circuit Current	74F		3.75	μA	0.0	V _{IOD} = 150 mV All Other Pins Grounded
I _{IL}	Input LOW Current			−1.2	mA	Max	V _{IN} = 0.5V
I _{OS}	Output Short-Circuit Current		−100	−225	mA	Max	V _{OUT} = 0V
I _{CCH}	Power Supply Current		3.7	6.0	mA	Max	V _O = HIGH
I _{CCL}	Power Supply Current		28.0	33.0	mA	Max	V _O = LOW

AC Electrical Characteristics: See Section 2 for Waveforms and Load Configurations

Symbol	Parameter	74F			74F		Units	Fig. No.		
		$T_A = +25^\circ C$ $V_{CC} = +5.0V$ $C_L = 50 \text{ pF}$			$T_A, V_{CC} = \text{Com}$ $C_L = 50 \text{ pF}$					
		Min	Typ	Max	Min	Max				
t_{PLH}	Propagation Delay A_n, B_n to \bar{O}_n	2.0 1.5	3.2 2.4	5.5 4.5	1.5 1.0	6.5 5.0	ns	2-3		